

isc N-Channel MOSFET Transistor

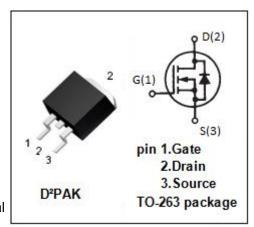
R6011ENJ

FEATURES

- Drain Current –I_D= 11A@ T_C=25 °C
- · Drain Source Voltage-
 - : V_{DSS}=600V(Min)
- Static Drain-Source On-Resistance
 - : $R_{DS(on)}$ = 390m Ω (Max)
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



• Designed for use in switch mode power supplies and general purpose applications.



ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	600	V
V _{GS}	Gate-Source Voltage-Continuous	±20	V
I _D	Drain Current-Continuous	11	А
I _{DM}	Drain Current-Single Pluse	22	А
P _D	Total Dissipation @T _C =25℃	124	W
TJ	Max. Operating Junction Temperature	-55~150	$^{\circ}$ C
T _{stg}	Storage Temperature	-55~150	$^{\circ}\mathbb{C}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	1.0	°C/W

	A B	K		L
J	D H		Q R	V
		m	m	V #
	DIM	MIN	MAX	
	A	1	0	1
	В	6.6	6.8	1
	C	15.23	15.25	1
	D	10.15	10.17	1
	F	0.76	0.78	1
	G	1.26	1.28 1.6	
	H	1.4	1.6	
	J	1.33	1.35	
	K	0.4	0.6	- 4
	L	4.6	4.8	
	Q	8.69 5.28	8.71	
	R		5.30	
		1.26	1.28	1
	S			
	U	0.0	0.2	

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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 1mA	600		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =1mA	2	4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 3.8A		390	mΩ
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V;V _{DS} = 0		±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 600V; V _{GS} = 0 V _{DS} = 600V; V _{GS} = 0@T _J =125°C		100 1000	μА
V _{SD}	Forward On-Voltage	I _S = 11A; V _{GS} = 0		1.5	V



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